

# isc Silicon PNP Power Transistor

# 2SB1292

#### **DESCRIPTION**

- High Collector Current:: Ic= -5A
- · Low Collector Saturation Voltage
  - :  $V_{CE(sat)}$ = -1.5 $V(Max)@I_{C}$ = -3A
- · Wide Area of Safe Operation
- Complement to Type 2SD1832
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

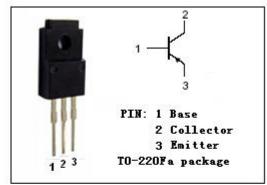


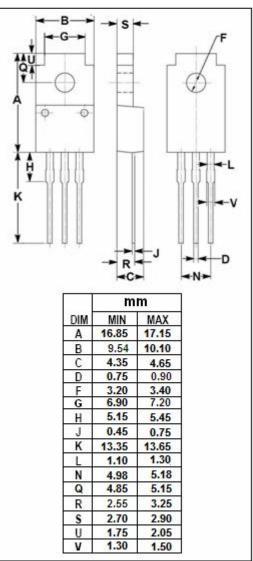
### **APPLICATIONS**

• Designed for low frequency power amplifier applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE		
Vсво	Collector-Base Voltage	V		
Vceo	Collector-Emitter Voltage -60			
V <sub>EBO</sub>	Emitter-Base Voltage	V		
Ic	Collector Current-Continuous -5			
I <sub>CM</sub>	Collector Current-Peak -10			
P <sub>C</sub>	Total Power Dissipation @ T <sub>a</sub> =25℃	2	W	
	Total Power Dissipation @ T <sub>C</sub> =25°C	30		
TJ	Junction Temperature	150	$^{\circ}$	
T <sub>stg</sub>	Storage Temperature Range -55~150		$^{\circ}\!\mathbb{C}$	







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### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -1mA; I <sub>B</sub> = 0	-60			V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I <sub>C</sub> = -50 μ A; I <sub>E</sub> = 0	-60			V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I <sub>E</sub> = -50 μ A; I <sub>C</sub> = 0	-5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -0.3A			-1.5	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -0.3A			-1.5	٧
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = -60V; I <sub>E</sub> = 0			-10	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -4V; I <sub>C</sub> = 0			-10	μА
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = -1A; V <sub>CE</sub> = -5V	100		320	

## h<sub>FE</sub> Classifications

E	F		
100-200	160-320		

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